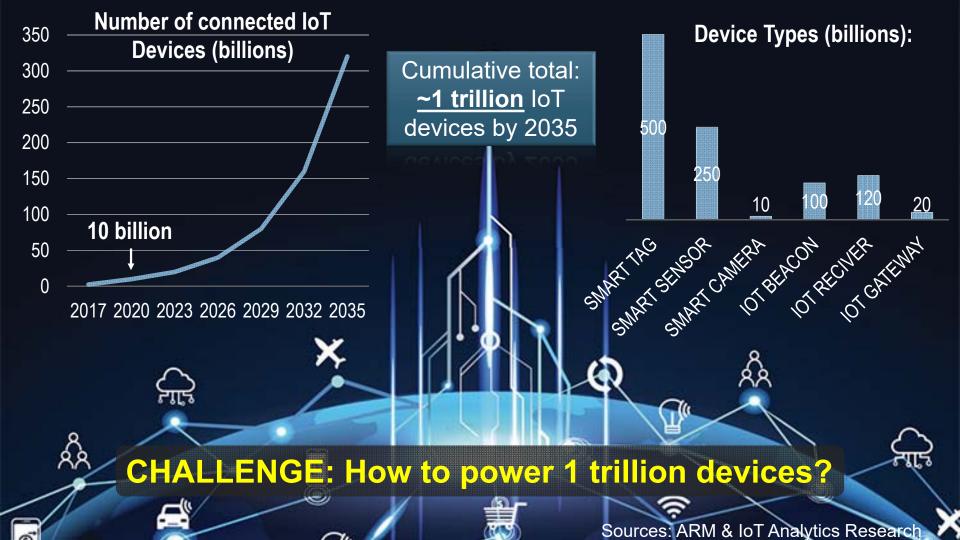




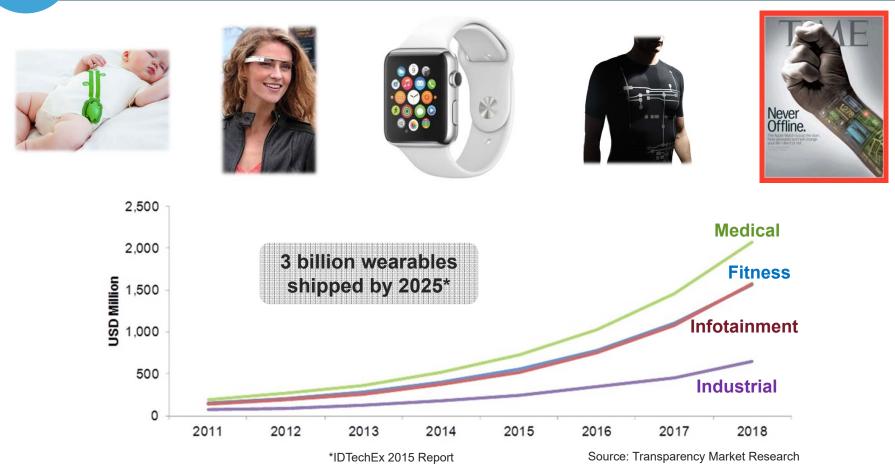
## Energy Harvesting and Self-Powered Sensing for Next-Generation "Unaware-ables" and IoT

Patrick Mercier University of California, San Diego



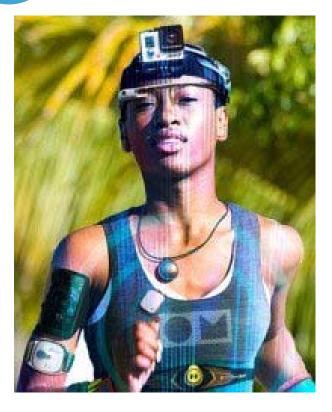
## 

#### Wearables: an exciting high-growth market





#### Why aren't we there now?



#### Size & Usability:

Need to develop sensors that are small & seamlessly integrated into daily life

#### **Battery Life:**

Need ultra-low-power and/or energy harvesting to minimize re-charging

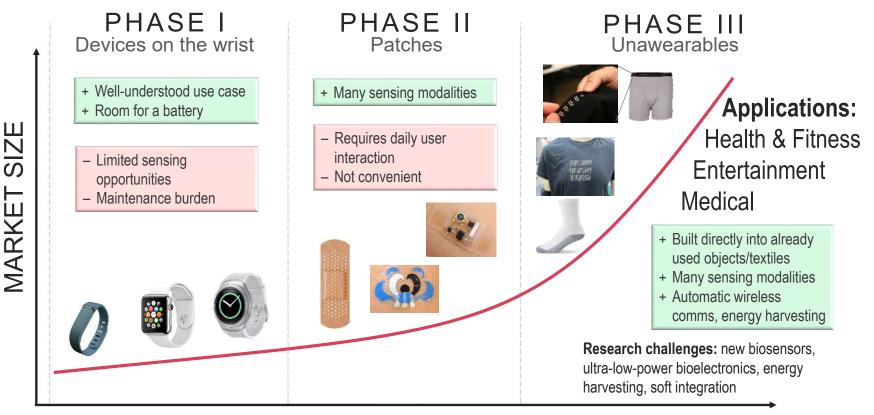
#### **Utility:**

Need to develop sensors that are <u>actually useful</u>

Mission: Address these issues through innovative transdisciplinary research

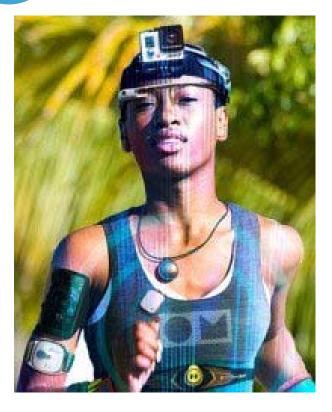


#### Wearables Roadmap





#### Why aren't we there now?



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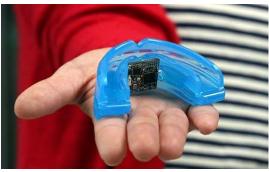
## 

# Pushing the frontier on new wearable sensing technologies

#### Non-invasive glucose and alcohol sensing



#### **Real-time saliva sensors**



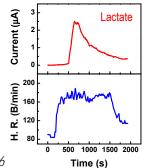
Physiochemical analysis in saliva

Startup company:

## Hybrid physiochemical & electrophysiological sensing

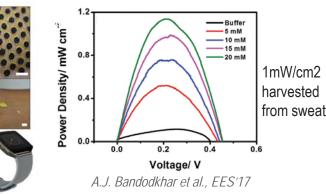


S. Imani et al., Nature Communications'16



First demonstration of real-time ECG+lactate recording

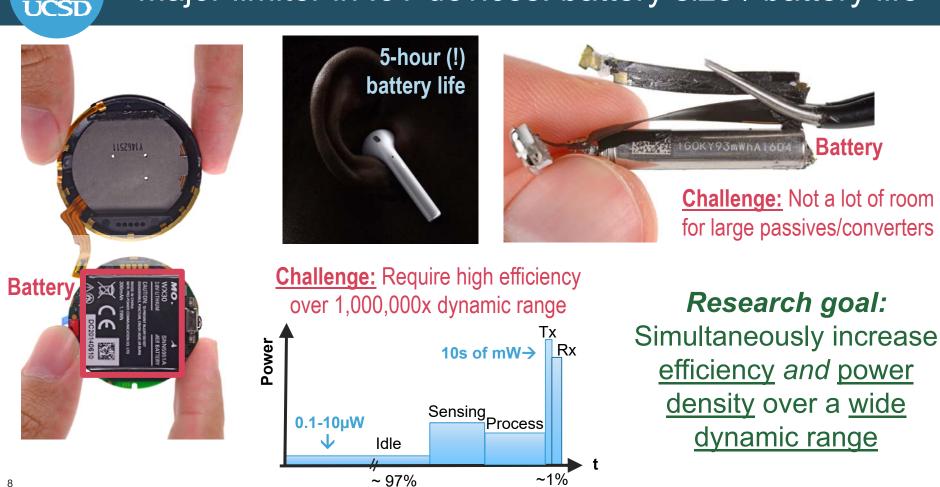
#### **Bio-energy harvesting**



J. Kim et al., Biosensors & Bioelectronics'15

7

## Major limiter in IoT devices: battery size / battery life

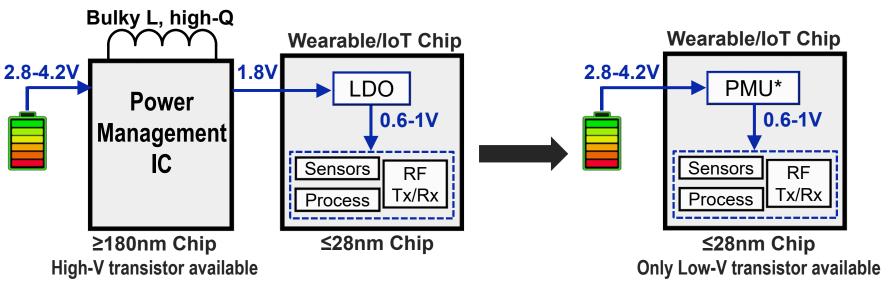




#### Powering IoT and Wearables in Scaled-CMOS

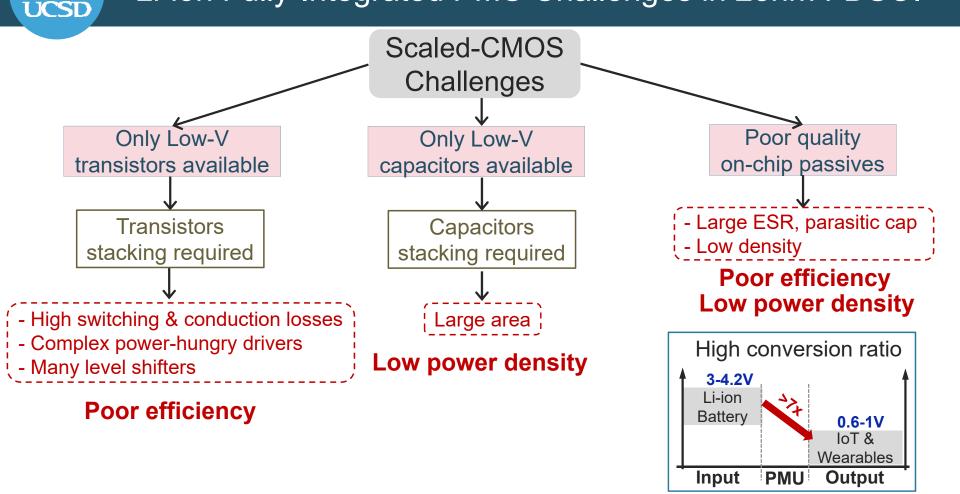




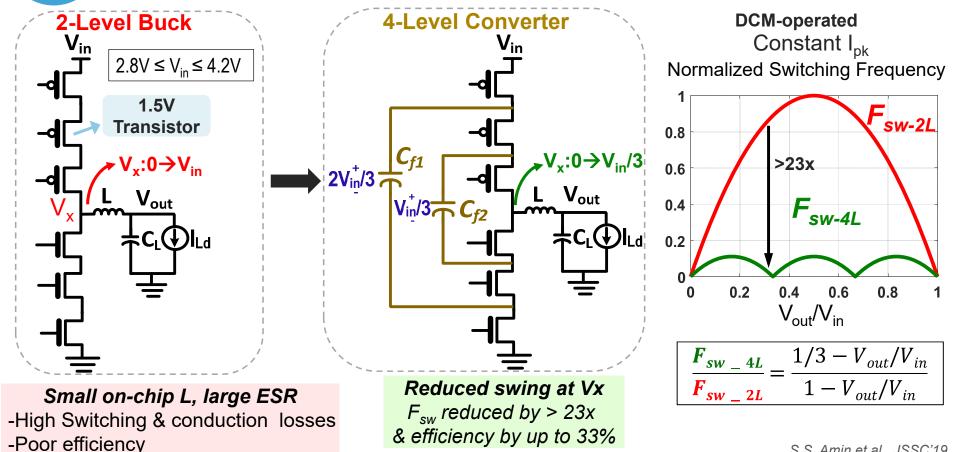


PMU\*: Power Management Unit with or without off-chip inductor

#### Li-ion Fully-Integrated PMU Challenges in 28nm FDSOI



## Towards Fully-Integrated Li-ion PMU in Scaled CMOS

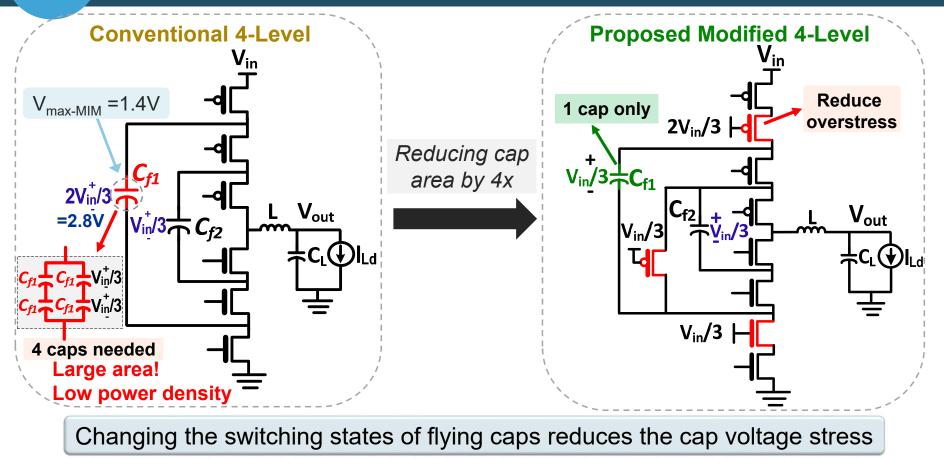


UCSL

S.S. Amin et al., JSSC'19

#### Conventional 4-Level Converter Area Penalty

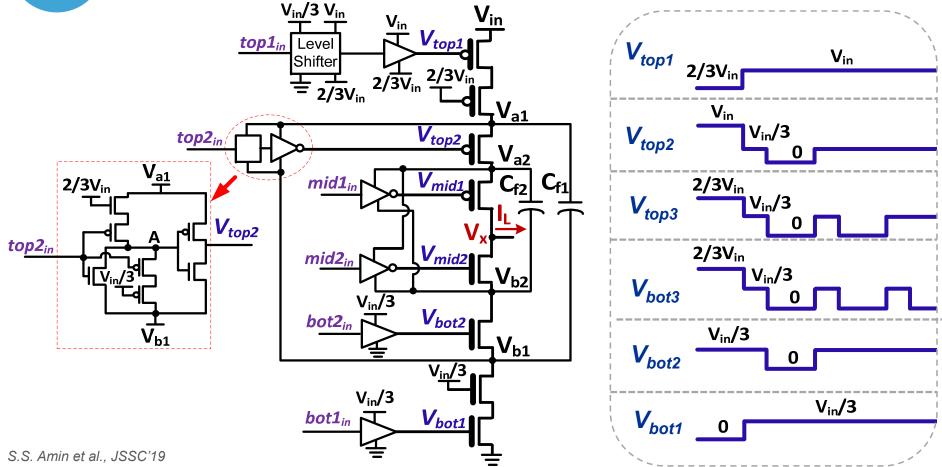
UCSD



S.S. Amin et al., JSSC'19

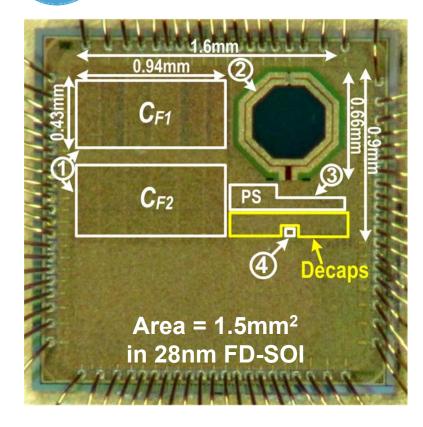


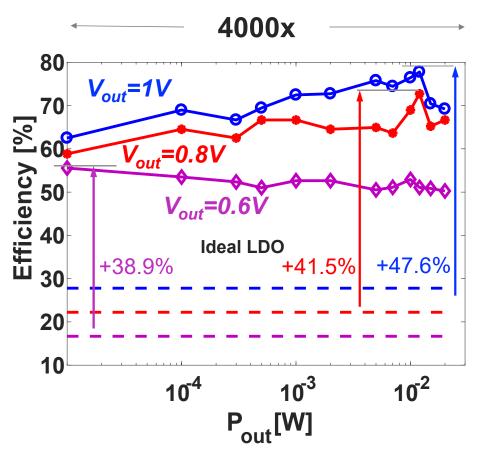
#### Driver Architecture



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#### **Measurement Results**

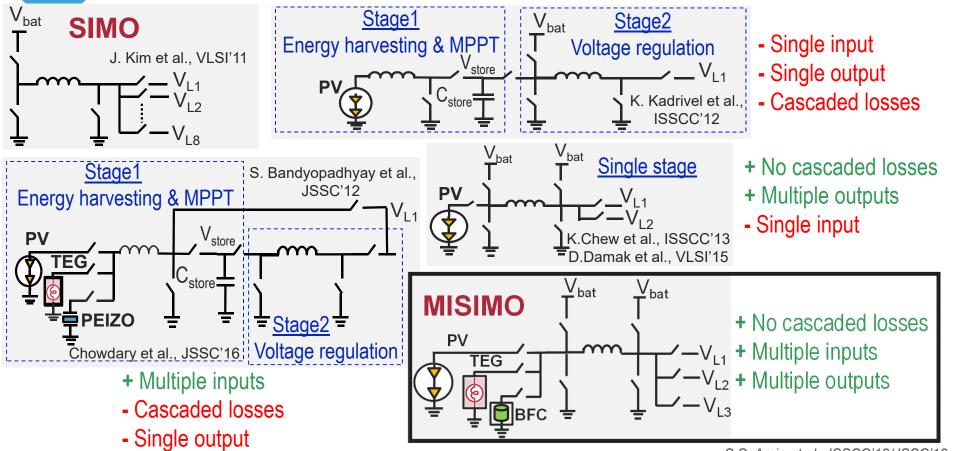




S.S. Amin et al., JSSC'19

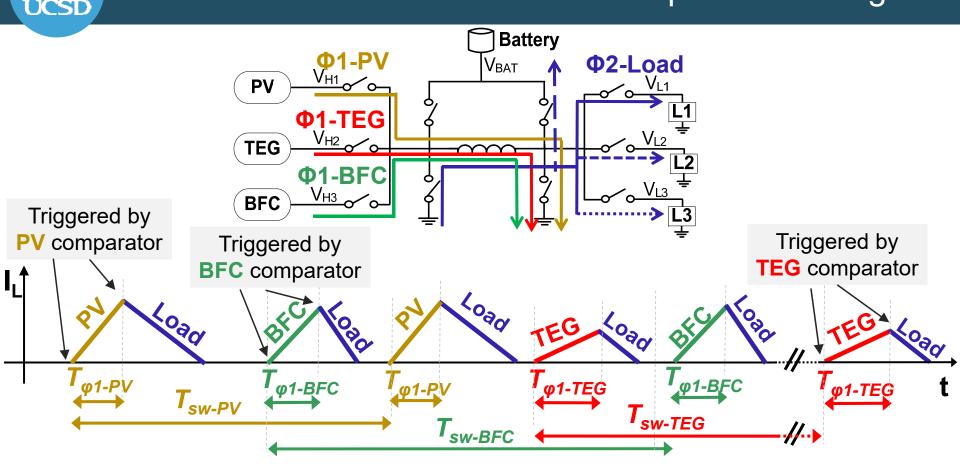
#### Towards Small Form-Factor Single-Inductor Converters

UCSD

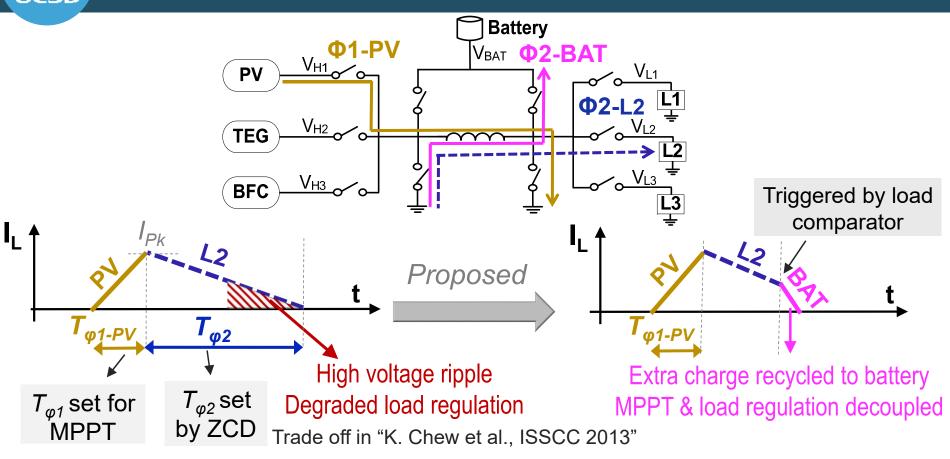


S.S. Amin et al., ISSCC'18/JSSC'18

#### Time-Shared Inductor for Multi-Input Harvesting

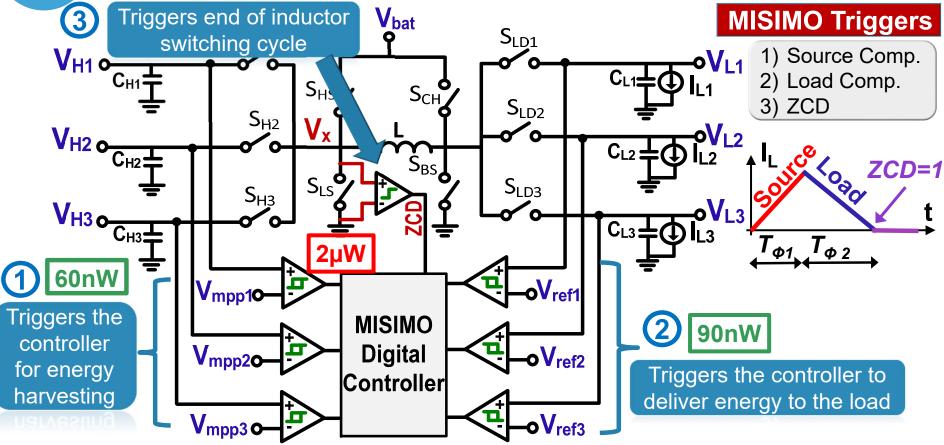


## Challenge: decoupling MPPT and Load Regulation





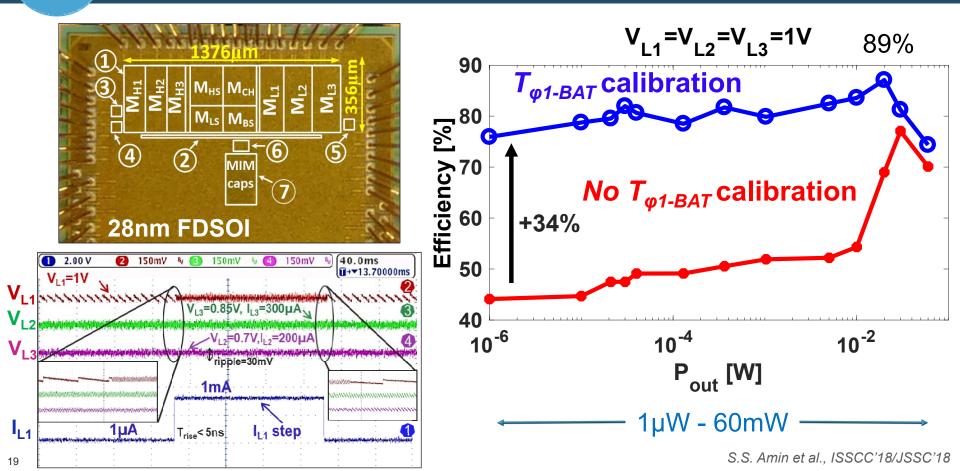
#### MISIMO Event Driven Controller



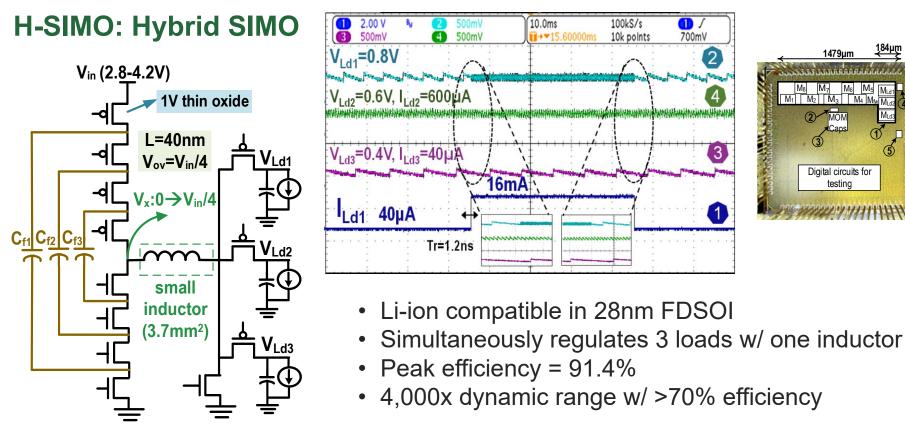
S.S. Amin et al., ISSCC'18/JSSC'18

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#### **MISIMO** Measurement Results



### Hybrid SIMO



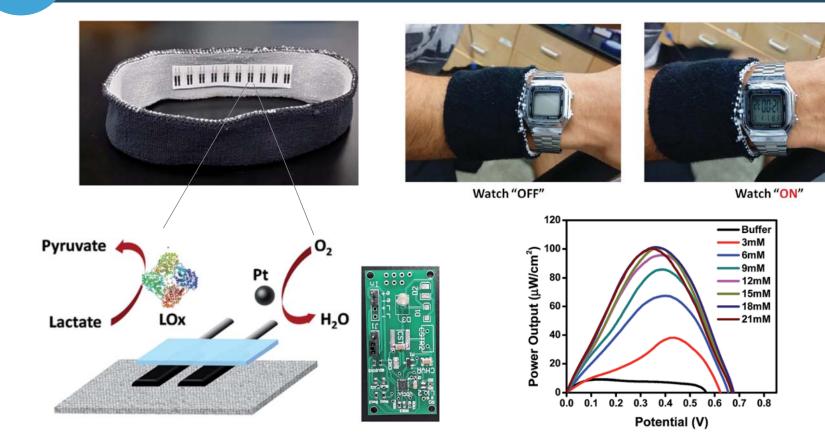
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for Wearable Sensors

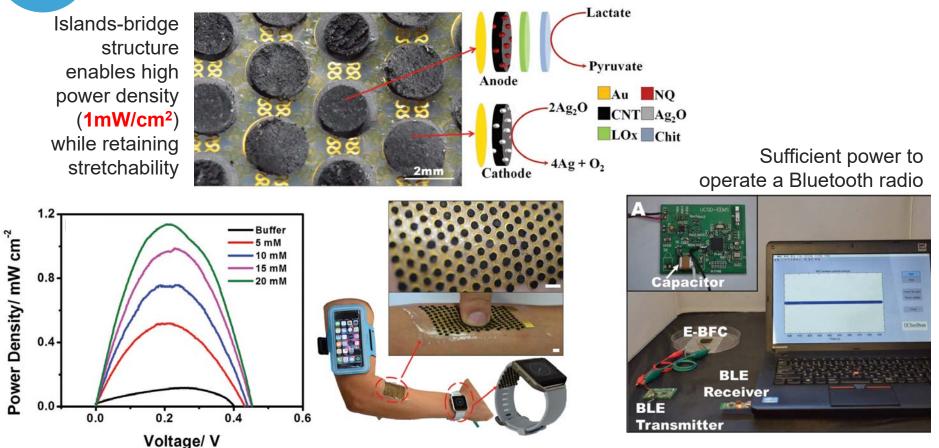
#### Harvesting energy from human perspiration via lactate biofuel cells



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J. Wenzhao et al., J. Mat. Chem., 2014

## Increasing BFC power density

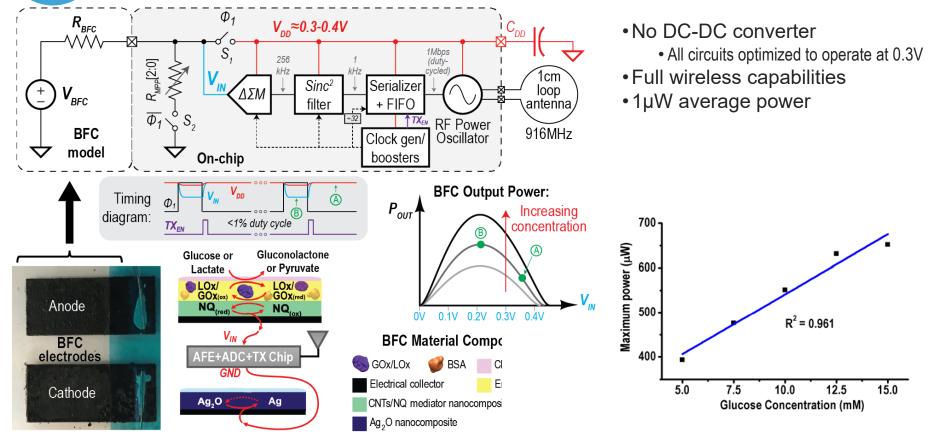


A.J. Bandodkar et al., Energy & Environmental Science, 2017

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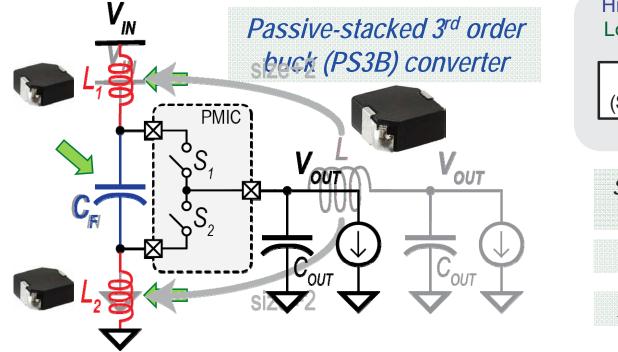
#### Self-powered glucose sensing

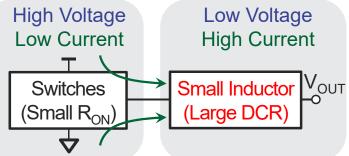


A.F. Yeknami et al., ISSCC/JSSC, 2018



#### Inductor-first conversion





Split into two half-sized inductors and stack at input

The input capacitor is now flying

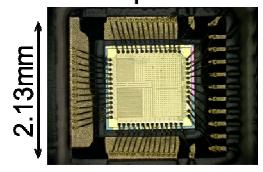
All passives are stacked at input

Inductors are placed at the low-current side of the converter

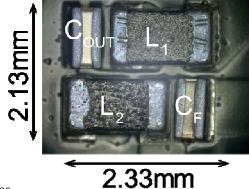
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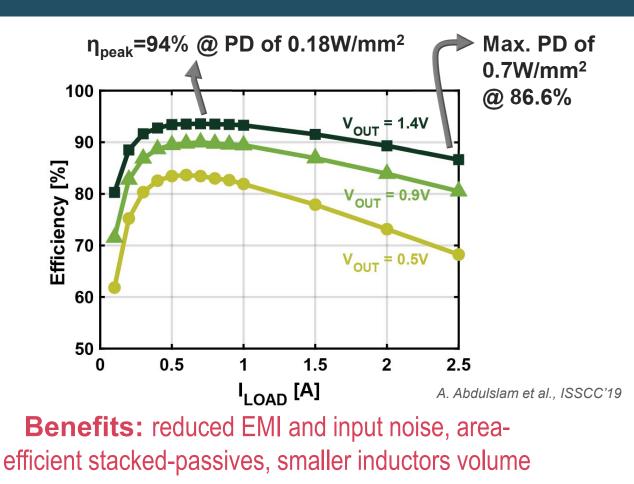
#### **PS3B Measurement Results**

Top-side



2.33mm Bottom-side





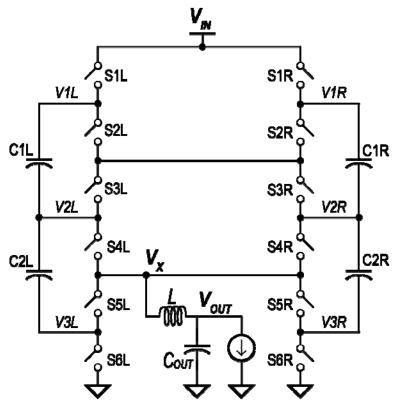


## Li-ion-compatible SMML Converter

- A symmetric modified multilevel ladder (SMML) converter:
  - Consists of two sides each with 2 capacitors and 6 switches.

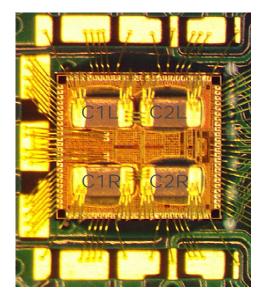
Features:

- ✓ Decreased conduction losses due to inherent phase interleaving.
- Minimum blocking voltage on all switches/capacitors.
- ✓ No need for voltage balancing modules flying capacitors are naturally stable.
- All necessary supplies are generated internally to power drivers and level shifters.

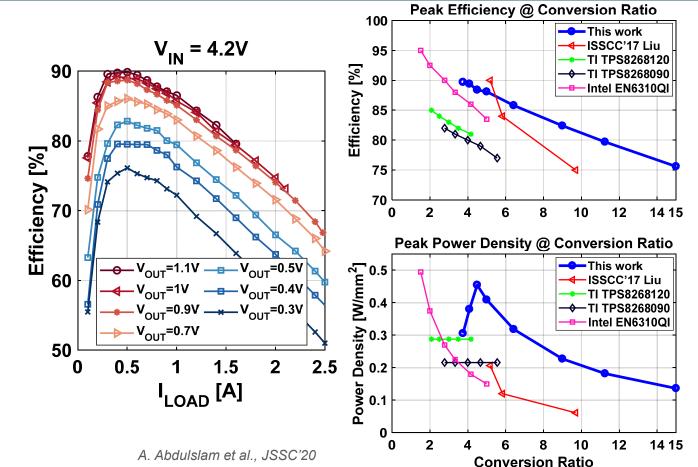


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#### SMML Measurement Results



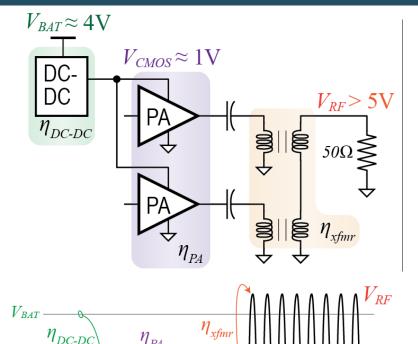
The inductor and the output capacitor are mounted under the chip



27



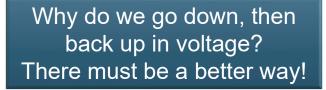
#### CMOS Power Amplifier Voltage Challenge



Idea: utilize many efficient ~1V class-D PAs and combine power with transformers

**Problem:** three voltage conversion stages leads to cascaded losses:

$$\eta_{tot} = \eta_{DC-DC} \, \eta_{PA} \, \eta_{xfmr} < 30\%$$



28

 $\eta_{DC-DC'}$ 

 $V_{CMOS}$ 

GND

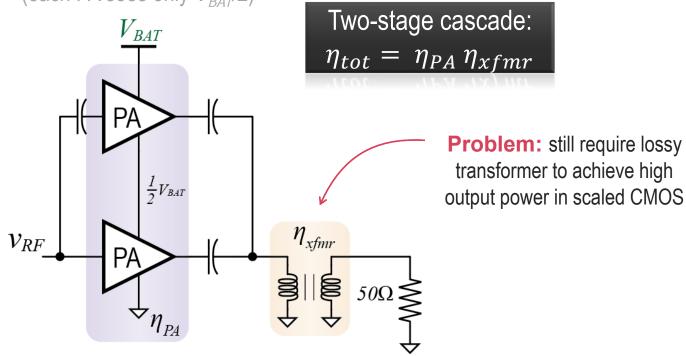
 $\eta_{PA}$ 



#### Partial Solution: PA Stacking

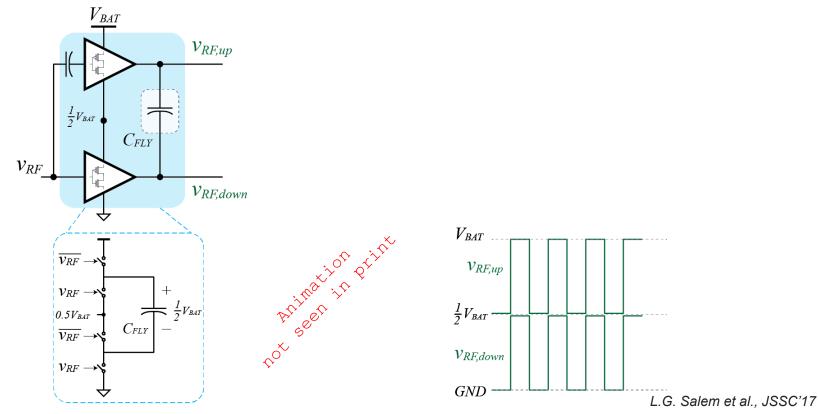
#### Stack entire class-D PAs for current re-use:

~100% efficient *implicit* DC-DC conversion (each PA sees only  $V_{B47}/2$ )



## Solid-State RF Impedance Transformation

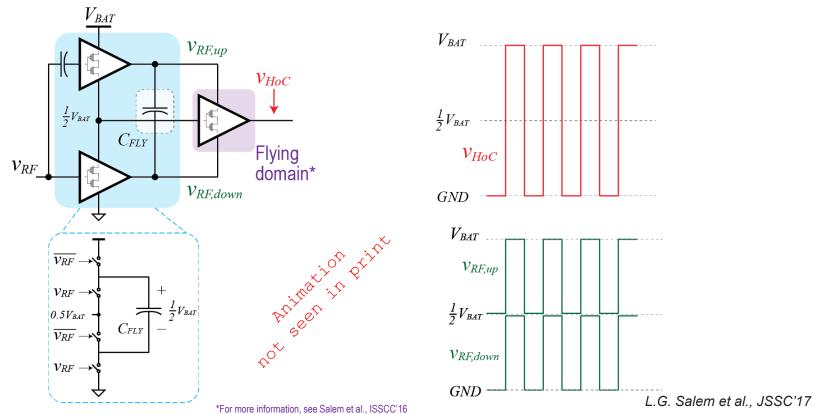
**Idea:** generate large RF voltages directly from a battery using ~1V devices by stacking PAs, then flying subsequent PAs between the rails of the prior stages in a *House-of-Cards* Topology



30

### Solid-State RF Impedance Transformation

**Idea:** generate large RF voltages directly from a battery using ~1V devices by stacking PAs, then flying subsequent PAs between the rails of the prior stages in a *House-of-Cards* Topology

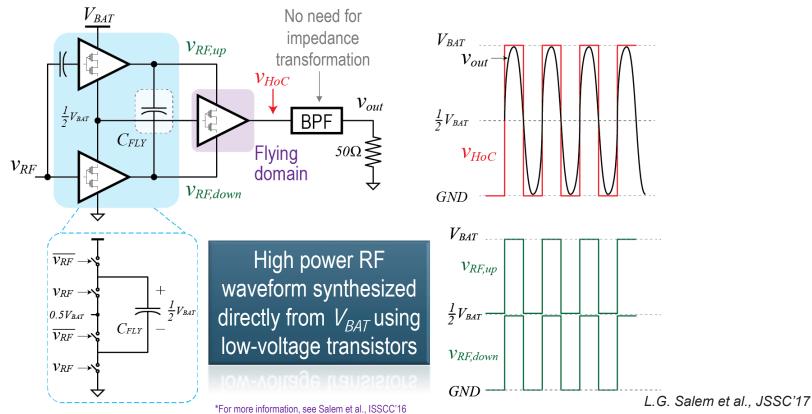


31

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### Solid-State RF Impedance Transformation

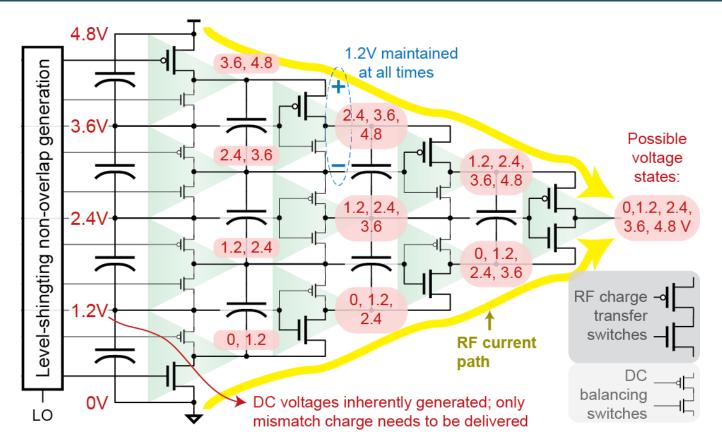
**Idea:** generate large RF voltages directly from a battery using ~1V devices by stacking PAs, then flying subsequent PAs between the rails of the prior stages in a *House-of-Cards* Topology



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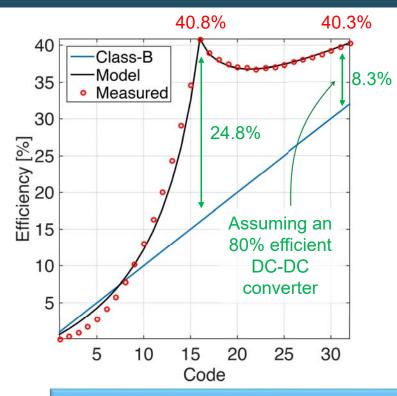
#### House-of-Cards (HoC) Schematic



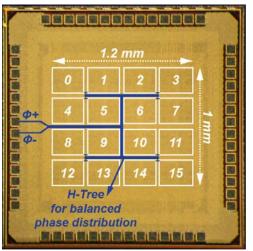
L.G. Salem et al., JSSC'17



#### Measurement results: PAE



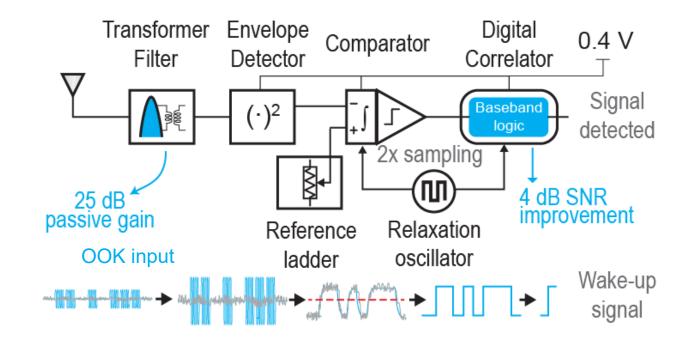
65nm LP 1.2V transistors Direct 4.8V Li-ion battery connection



>40% battery-to-RF power-added efficiency at both peak power (23dBm) and at 6dB backoff

L.G. Salem et al., JSSC'17

#### A nW Wake-up Receiver



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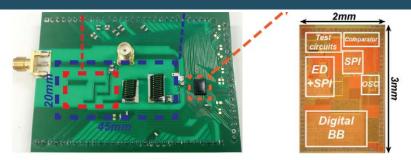
High *R*<sub>in</sub> ED supports high passive gain front-end w/ high-*Q* filtering at low power

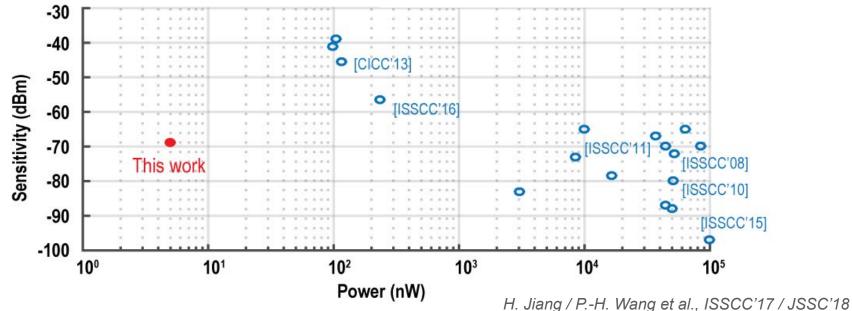
H. Jiang / P.-H. Wang et al., ISSCC'17 / JSSC'18



#### WuRX Measurement Results

- Power consumption: 4.5nW
- Sensitivity: -69dBm
- Wake-up latency: 53ms



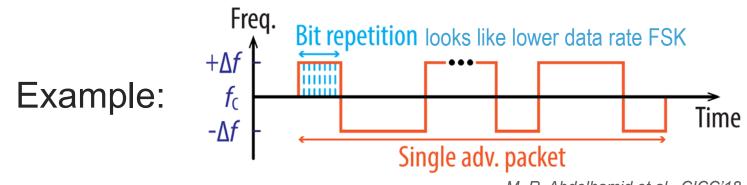


Most standards use <u>complex modulation</u> at <u>high data rates</u>  $\rightarrow$  difficult to build an ultra-low-power RX w/ good sensitivity

Back-channel communication

N. E. Roberts et al., ISSCC'16

Hack a standard-compliant signal to look like a simpler, lower bandwidth modulation



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#### An Interference-Robust BLE-Compliant WuRX

#### BLE advertising channels and wireless co-existance @ 2.4GHz ISM band BLE advertising event structure Direct channel-filtering using 0.25mm<sup>2</sup> single-die 3-channel FBAR RSSI TX low duty cycle mode single adv. event≤20ms Ch. 37 Ch. 38 Ch. 39 Time $\leq 10 \text{ms}$ $\leq 10 \text{ms}$ Ch. 39 Ch. 37 WLAN Ch.38 WLAN WLAN 2402MHz Ch. 1 2426MHz Ch. 6 Ch. 11 2480MHz Matching network BB PGA+LPF Comparator IF LNA Wake-up Frequency-hoping BB 000-× DSP between advertising fLO,RF f<sub>LO.IF</sub> channels enables TPLL Divider **Oversampling** IF Osc Single-die interference-resilient **3-channel FBAR** detection **Channel selection**

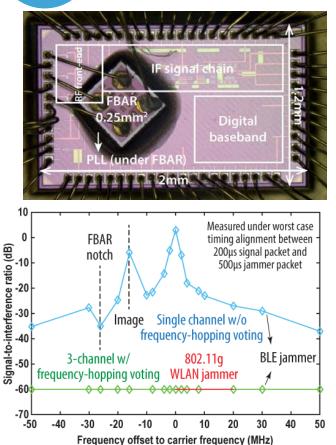
P.-H. Wang et al., ISSCC'19

Frea

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## 

### An Interference-Robust BLE-Compliant WuRX

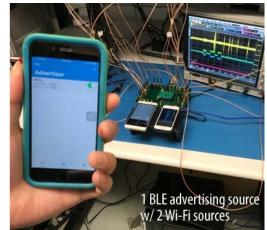


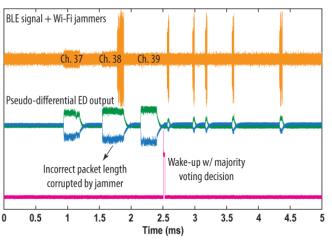
□ Sensitivity: -85dBm @ 220µW

□ 27.5dB better than prior-art

**Latency:** 200µs-to-1.47ms

SIR: at least -60dB SIR (limited by measurement setup)





P.-H. Wang et al., ISSCC'19



#### Conclusions

- Next generation IoT devices require:
  - New sensors and sensing techniques
  - Small form factors
  - Long/infinite battery life  $\rightarrow$  often limited by radios
- Meet these needs through:

Application Engineering	<ul> <li>New communication paradigms</li> <li>New sensor development</li> </ul>	
Architectural Innovations	<ul> <li>New sensor transduction/digitization techniques</li> <li>New power conversion circuit topologies</li> </ul>	Exciting new IoT applicationsI
New Circuit Techniques	<ul> <li>Topologically-defined "digitally-replaced analog"</li> <li>Deep subthreshold DTMOS</li> </ul>	



#### Acknowledgements















National Institute of Biomedical Imaging and Bioengineering

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